## NSN 5961-01-086-0076

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View Online at https://aerobasegroup.com/nsn/5961-01-086-0076 **Inclosure Material:** Metal **Overall Length:** 0.450 inches **Overall Height:** 0.130 inches **Overall Width:** 0.330 inches **Overall Diameter:** 0.090 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 breakdown voltage, collector-to-base, emitter open and 6.0 emitter to base voltage, static, collector open and 80.0 collector to emitter voltage/static/base open **Current Rating Per Characteristic:** 2.00 amperes source cutoff current and 1.00 amperes source cutoff current **Power Rating Per Characteristic:** 12.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 165.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 3 uninsulated wire lead **Specification Data:** 80131-release6470 professional/industrial association specification Shelf Life: N/a **Unit Of Measure:** 

No

Demilitarization:

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